NSN 5961-00-492-7780

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-492-7780 **Inclosure Material:** Metal **Overall Length:** Between 0.150 inches and 0.180 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 40.0 breakdown voltage, collector-to-emitter, base open all transistor and 60.0 collector to base voltage, dc all transistor and 5.0 emitter to base voltage, instantaneous all transistor **Current Rating Per Characteristic:** 300.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0